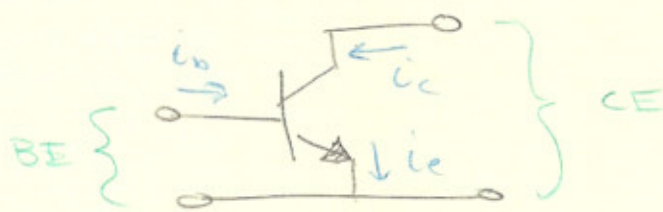


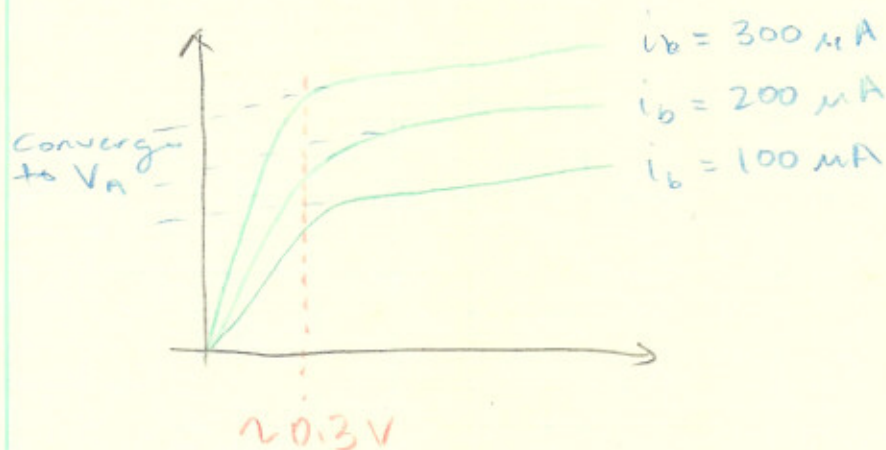
Process of design

1. Enumerate objectives of design.
2. Generate a list of possible ways to achieve objectives.
3. Review and select best alternative
4. Do analysis of remaining options

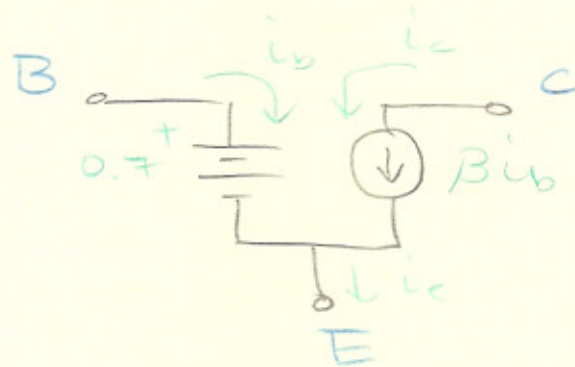
Common Emitter amplifier

$$\left. \begin{aligned} i_e &= i_c + i_b \\ i_c &= \beta i_b \end{aligned} \right\} \text{during active region.}$$

$$25 < \beta < 250$$



If $V_A \rightarrow \infty$ the transistor's collector behaves as a current source



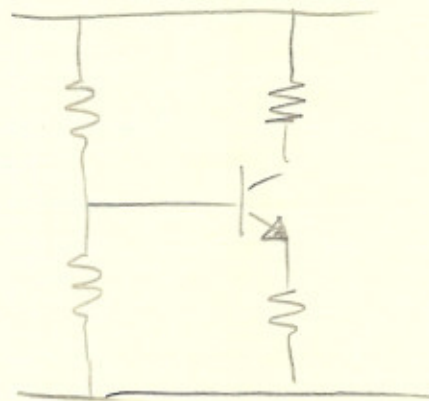
Typically for discrete transmitter

$$V_A \sim 40 \rightarrow 100$$

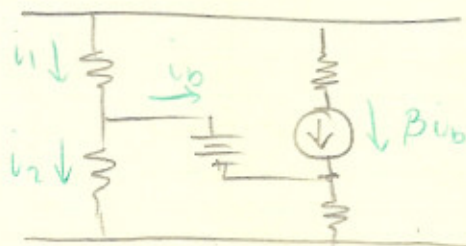
For finding bias point of a transistor in hand analysis we often assume $V_A \rightarrow \infty$

For some small signal analysis, V_A is considered... no.... biasing.

* Biasing



Assume Q is in Active region



3.
Assume $I_B = 0$ and calculate I_1 , compare I_1 with I_{Cmax} ; if

$$I_1 \gg \frac{I_{Cmax}}{\beta}$$

Then we can neglect I_B in I_1 calculation.
Normally $I_1 \neq I_2 \gg I_B$; then we can say

$$V_B \sim V_{CC} \frac{R_2}{R_1 + R_2}$$

$$I_C = \frac{\beta}{\beta + 1} \cdot \frac{V_B - 0.7}{R_E}$$